查询74LVT14D供应商

INTEGRATED CIRCUITSPCB打样工厂, 24小时加急出



Product specification IC24 Data Handbook

1996 Aug 28







74LVT14

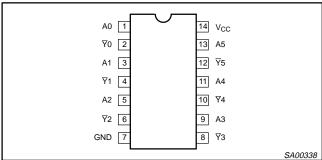
DESCRIPTION

The 74LVT14 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V. They are capable of transforming slowly changing input signals into sharply defined, jitter free output signals. In addition, they have greater noise margin than conventional inverters. Each circuit contains a Schmitt trigger followed by a Darlington level shifter and a phase splitter driving a TTL totem-pole output. The Schmitt trigger uses positive feedback to effectively speed-up slow input transitions, and provide different input threshold voltages for positive-going and negative-going input threshold (typically 600mV) is determined internally by resistor ratios and is insensitive to temperature and supply voltage variations.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An to Yn	$C_L = 50 pF;$ $V_{CC} = 3.3 V$	3.2 3.0	ns
C _{IN}	Input capacitance	V _I = 0V or 3.0V	3	pF
I _{CCL}	Total supply current	Outputs low; $V_{CC} = 3.6V$	1.5	mA

PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 3, 5, 9, 11, 13	An	Data inputs
2, 4, 6, 8, 10, 12	Ϋ́n	Data outputs
7	GND	Ground (0V)
14	V _{CC}	Positive supply voltage

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	-40°C to +85°C	74LVT14 D	74LVT14 D	SOT108-1
14-Pin Plastic SSOP	–40°C to +85°C	74LVT14 DB	74LVT14 DB	SOT337-1
14-Pin Plastic TSSOP	–40°C to +85°C	74LVT14 PW	74LVT14 PWDH	SOT402-1

FUNCTION TABLE

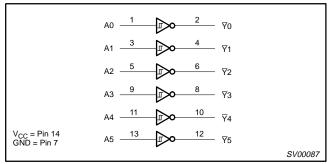
INPUTS	OUTPUT
Dn	Qn
L	Н
Н	L

NOTES:

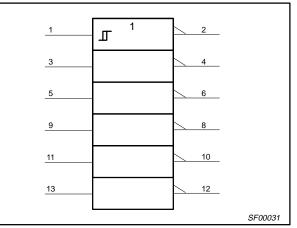
H = High voltage level

L = Low voltage level

LOGIC DIAGRAM

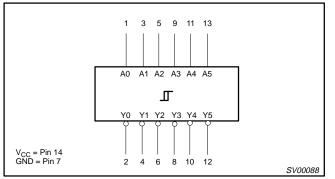


IEC/IEEE SYMBOL



74LVT14

LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
IIK DC input diode current		V _I < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
		Output in High state	-32	
IOUT	DC output current	Output in Low state	64	- mA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

 The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STMBOL	PARAMETER	MIN	MAX	
V _{CC}	DC supply voltage		3.6	V
VI	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Low-level Input voltage		0.8	V
I _{ОН}	High-level output current		-20	mA
I _{OL}	Low-level output current		32	mA
$\Delta t/\Delta v$	At/∆v Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	T _{amb} Operating free-air temperature range		+85	°C

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions Voltages are referenced to GND (ground = 0V)

			I	LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = ·	-40°C to	+85°C		
			MIN	TYP ¹	MAX	1	
V _{T+}	Positive-going threshold	$V_{CC} = 3.3V$	1.5	1.7	2.0	V	
V _{T-}	Negative-going threshold	$V_{CC} = 3.3V$	0.9	1.1	1.3	V	
ΔV_{T}	Hysteresis	$V_{CC} = 3.3V$	0.4	0.6		V	
V _{IK}	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$			-1.2	V	
V _{OH}		$V_{CC} = 2.7$ to 3.6V; $I_{OH} = -100\mu A$	V _{CC} -0.2				
	High-level output voltage	$V_{CC} = 2.7V; I_{OH} = -6mA$	2.4			V	
		$V_{CC} = 3.0V; I_{OH} = -20mA$	2.0				
		$V_{CC} = 2.7 V; I_{OL} = 100 \mu A$			0.2	V	
V _{OL}	Low-level output voltage	V _{CC} = 2.7V; I _{OL} = 24mA			0.5		
		V _{CC} = 3.0V; I _{OL} = 32mA			0.5		
L	Input leakage current	$V_{CC} = 0 \text{ or } 3.6 \text{V}; \text{ V}_{\text{I}} = 5.5 \text{V}$			10	μA	
łı	input leakage current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or } GND$		±1			
I _{OFF}	Output off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$			±100	μΑ	
I _{CCH}	Quiescent supply current	V_{CC} = 3.6V; Outputs High, V_{I} = GND or V_{CC} , I_{O} = 0			0.02	– mA	
I _{CCL}		V_{CC} = 3.6V; Outputs Low, V_{I} = GND or $V_{CC,}$ I_{O} = 0		1.5	3		
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND			0.2	μA	
CI	Input capacitance	V ₁ = 3V or 0		3		pF	

NOTES:

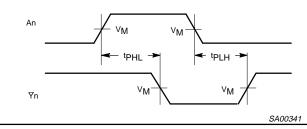
1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^{\circ}C$. 2. This is the increase in supply current for each input at the specificed voltage level other than V_{CC} or GND

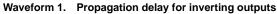
AC ELECTRICAL CHARACTERISTICS

		TEAT		I	IMITS		
SYMBOL	PARAMETER	TEST CONDITION	Vc	_{:C} = 3.3V ±0.	3V	V _{CC} = 2.7V	UNIT
			MIN	ТҮР	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay An to Yn	Waveform 1	1.0 1.0	3.8 3.2	5.7 4.5	6.9 4.1	ns

AC WAVEFORMS

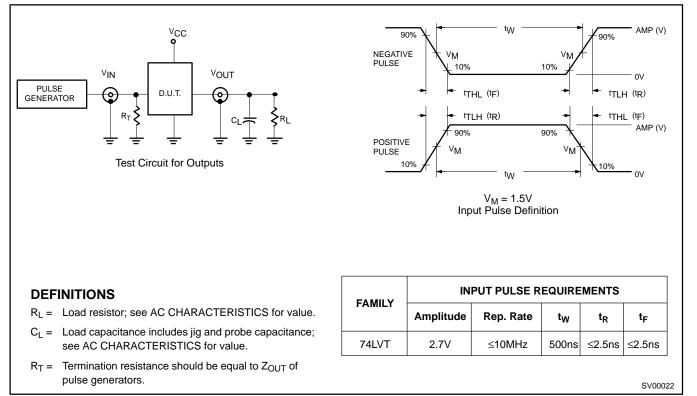
 $V_{\rm M}$ = 1.5V, $V_{\rm IN}$ = GND to 2.7V



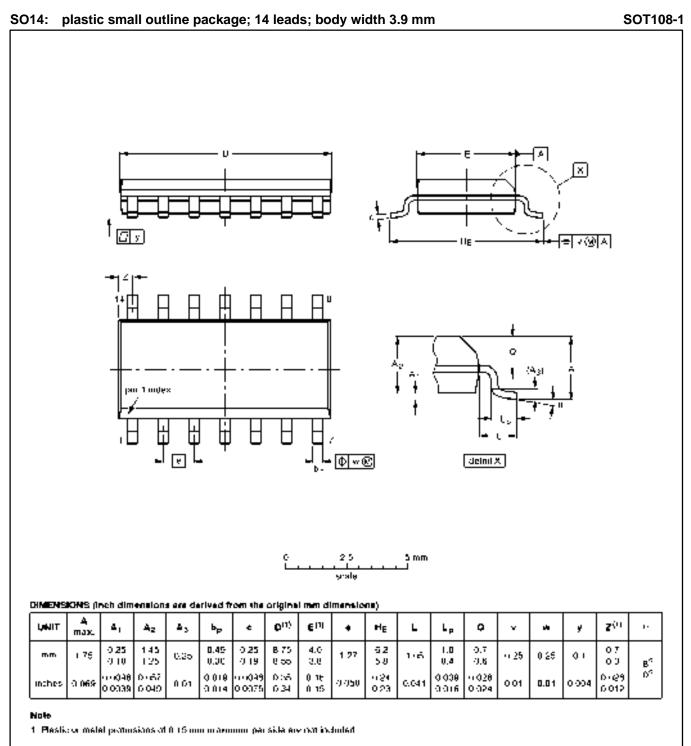


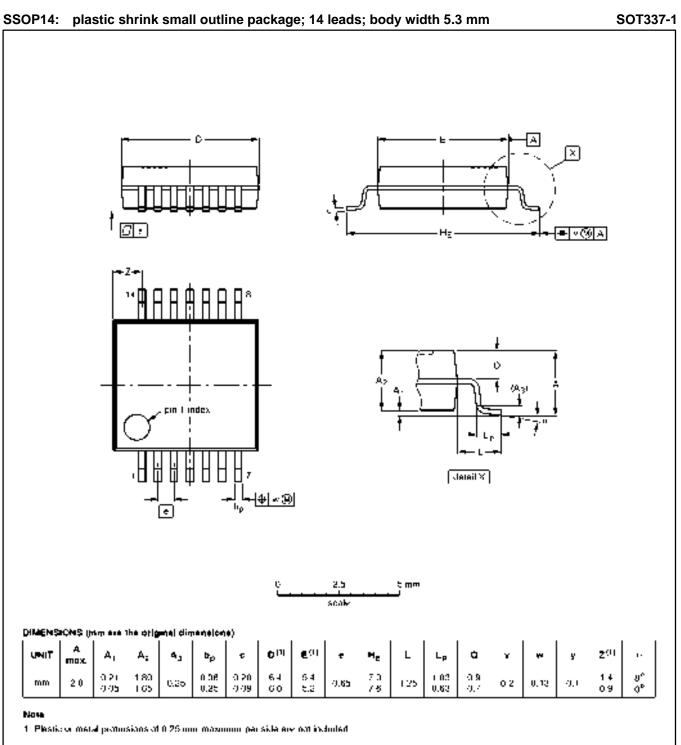
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TEST CIRCUIT AND WAVEFORMS



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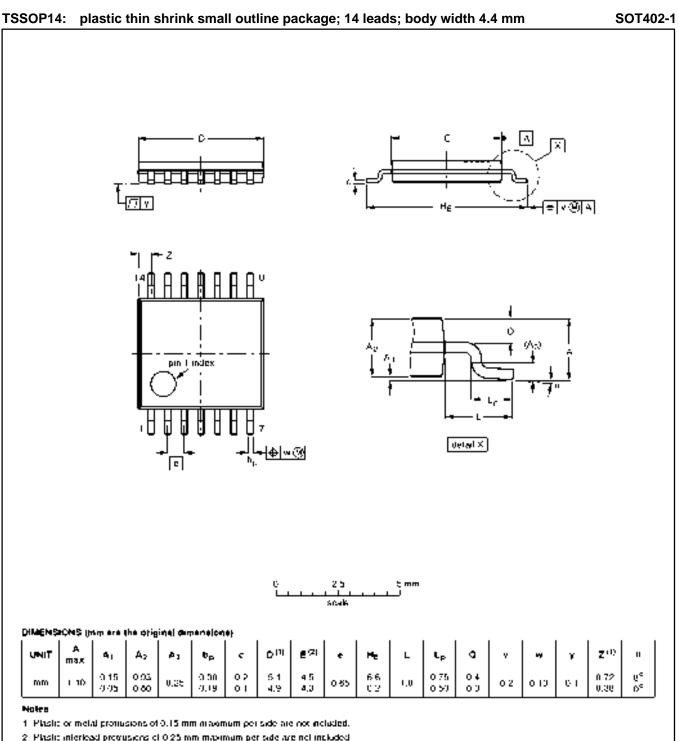




OUTLINE		REFER	IENCES	EUROPEAN	
VERBION	IEC	JEDEC	EITÌ	PROJECTION	IBBUE DATE
SOTODAN		мо-тьоАБ		€∃\$	- 95-82-94 96-01-19

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I	OUTLINE		REFERENCES			EUROPEAN ISSUE DATE		
	VERBION	IEC	JEDEC	EI4J		PROJECTION	ISSUE DATE	
	SQT402-1		M:0+150			€∃\$	- 54-07-12 85-14-04	

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NOTES

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DEFINITIONS			
Data Sheet Identification	Product Status	Definition	
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.	
Preliminary Specification Preproduction Product		This data sheet contains preliminary data, and supplementary data will be published at a later date. Ph Semiconductors reserves the right to make changes at any time without notice in order to improve de and supply the best possible product.	
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